

General Description

The WSP4986 is the highest performance trench N-ch MOSFET with extreme high cell density , which provide excellent R_{DSON} and gate charge for most of the synchronous buck converter applications .

The WSP4986 meet the RoHS and Green Product requirement , 100% EAS guaranteed with full function reliability approved.

Features

- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent CdV/dt effect decline
- 100% EAS Guaranteed
- Green Device Available

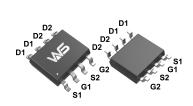
Product Summery

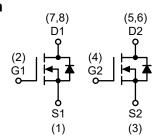
BV _{DSS}	R _{DSON}	I _D		
40V	13.7mΩ	12A		

Applications

- High Frequency Point-of-Load Synchronous Buck Converter for MB/NB/UMPC/VGA
- Networking DC-DC Power System
- Load Switch

SOP-8L Pin Configuration





Absolute Maximum Ratings

Symbol	Parameter	Rating	Units
V_{DS}	Drain-Source Voltage	40	V
V_{GS}	Gate-Source Voltage	±20	V
I _D @T _C =25℃	Continuous Drain Current, V _{GS} @ 10V ¹	12	А
I _D @T _C =70°C	Continuous Drain Current, V _{GS} @ 10V ¹	6.6	Α
I _{DM}	Pulsed Drain Current ²	35	А
EAS	Single Pulse Avalanche Energy ³	20	mJ
I _{AS}	Avalanche Current	15	Α
P _D @T _A =25°C	Total Power Dissipation⁴	2.5	W
T _{STG}	Storage Temperature Range	-55 to 150	°C
T_J	Operating Junction Temperature Range -55 to 150		$^{\circ}$ C

Thermal Data

Symbol	Parameter		Max.	Unit
$R_{ heta JA}$	Thermal Resistance Junction-ambient ¹	ce Junction-ambient 1		°C/W
$R_{ heta JC}$	Thermal Resistance Junction-Case ¹		50	°C/W



Electrical Characteristics (T_J=25 ℃, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit	
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =250uA	40			V	
$\triangle BV_{DSS}/\triangle T_{J}$	BVDSS Temperature Coefficient	Reference to 25°C , I _D =1mA		0.044		V/°C	
В	21 11 12 12 12 12 12 12 12 12 12 12 12 1	V _{GS} =10V , I _D =2A		13.7	15	 0	
R _{DS(ON)}	Static Drain-Source On-Resistance ²	V _{GS} =4.5V , I _D =2A		17	20	mΩ	
V _{GS(th)}	Gate Threshold Voltage	\/ -\/ -250A	1.0	1.5	2.5	V	
$\triangle V_{GS(th)}$	V _{GS(th)} Temperature Coefficient	$V_{GS}=V_{DS}$, $I_D=250uA$		-3.8		mV/℃	
	Drain Source Leakage Current	V_{DS} =24V , V_{GS} =0V , T_J =25 $^{\circ}$ C			1	1	
I _{DSS}	Drain-Source Leakage Current	V_{DS} =24V , V_{GS} =0V , T_J =55 $^{\circ}$ C			5	uA	
I _{GSS}	Gate-Source Leakage Current	V_{GS} = $\pm 20V$, V_{DS} = $0V$			±100	nA	
gfs	Forward Transconductance	V _{DS} =5V , I _D =4A		25		S	
R_{g}	Gate Resistance	V _{DS} =0V , V _{GS} =0V , f=1MHz		2.5	5	Ω	
Qg	Total Gate Charge (10V)			23			
Q_gs	Gate-Source Charge	V_{DS} =20V , V_{GS} =10V , I_{D} =2A		3.6		nC	
Q_{gd}	Gate-Drain Charge			6.4			
T _{d(on)}	Turn-On Delay Time			5.2			
Tr	Rise Time V_{DD} =20V , V_{GEN} =10V , R_{G} =6 Ω			14		20	
T _{d(off)}	Turn-Off Delay Time	Delay Time I _D =4A ,R _L =30Ω		23		ns	
T _f	Fall Time			11			
C _{iss}	Input Capacitance			950			
Coss	Output Capacitance	V _{DS} =20V , V _{GS} =0V , f=1MHz		102		pF	
C _{rss}	C _{rss} Reverse Transfer Capacitance			60			

Guaranteed Avalanche Characteristics

Symbol	Parameter Conditions		Min.	Тур.	Max.	Unit
EAS	Single Pulse Avalanche Energy ⁵	V _{DD} =20V , L=0.1mH , I _{AS} =15A	20			mJ

Diode Characteristics

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
Is	Continuous Source Current ^{1,6}	V =V =0V Force Current			5.0	Α
I _{SM}	Pulsed Source Current ^{2,6}	V _G =V _D =0V , Force Current			14	Α
V _{SD}	Diode Forward Voltage ²	V_{GS} =0V , I_{S} =1A , T_{J} =25 $^{\circ}$ C			1.1	V
t _{rr}	Reverse Recovery Time			18		nS
Q _{rr}	Reverse Recovery Charge	IF=6.3A , dI/dt=100A/ μ s , T $_{J}$ =25 $^{\circ}$ C		16		nC

Note:

- 1. The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper,t<10sec.
- 2.The data tested by pulsed , pulse width $\leq 300 \text{us}$, duty cycle $\leq 2\%$
- 3. The EAS data shows Max. rating . The test condition is V_{DD} =25V, V_{GS} =10V, L=0.1mH, I_{AS} =12A
- 5.The Min. value is 100% EAS tested guarantee.
- 6. The data is theoretically the same as I_D and I_{DM} , in real applications, should be limited by total power dissipation.



Typical Characteristics

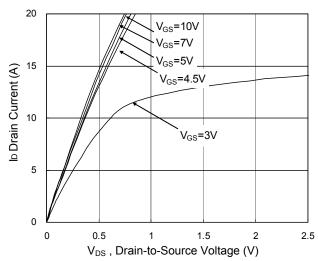


Fig.1 Typical Output Characteristics

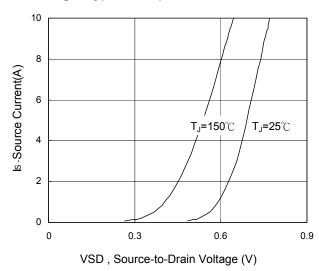


Fig.3 Forward Characteristics Of Reverse

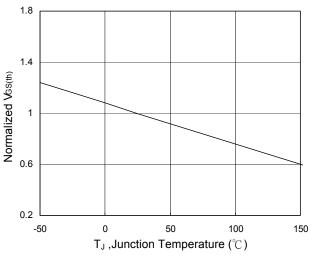


Fig.5 Normalized $V_{\text{GS(th)}}$ vs. T_{J}

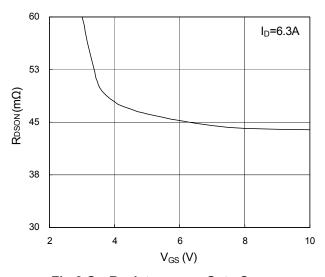


Fig.2 On-Resistance vs. Gate-Source

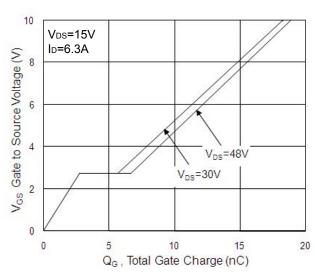


Fig.4 Gate-Charge Characteristics

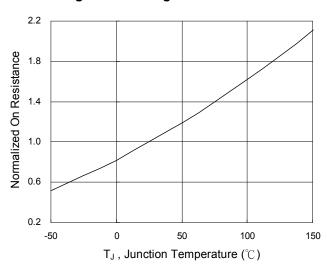
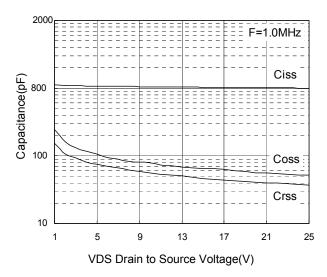


Fig.6 Normalized R_{DSON} vs. T_J





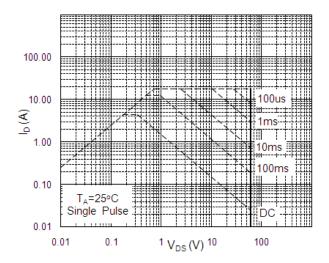


Fig.7 Capacitance

Fig.8 Safe Operating Area

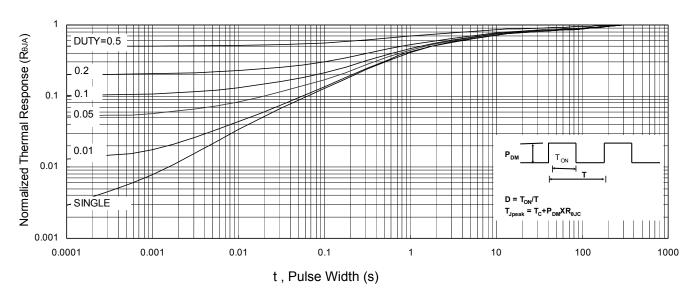


Fig.9 Normalized Maximum Transient Thermal Impedance

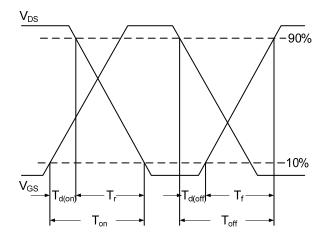


Fig.10 Switching Time Waveform

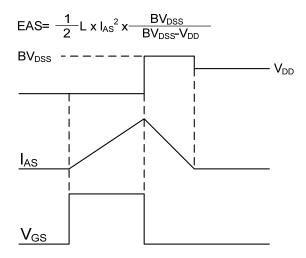
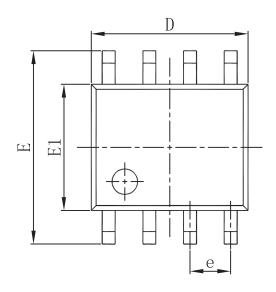


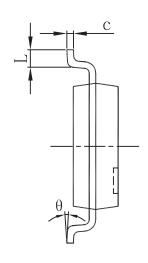
Fig.11 Unclamped Inductive Switching Waveform

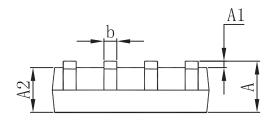




Packaging information







Comple al	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
A	1. 350	1.750	0.053	0.069	
A1	0. 100	0. 250	0.004	0.010	
A2	1. 350	1. 550	0. 053	0.061	
b	0. 330	0. 510	0.013	0.020	
c	0. 170	0. 250	0.007	0.010	
D	4.800	5. 000	0. 189	0. 197	
e	1.270 (BSC)		0.050 (BSC)		
Е	5. 800	6. 200	0. 228	0.244	
E1	3.800	4. 000	0. 150	0. 157	
L	0.400	1. 270	0.016	0.050	
θ	0°	8°	0°	8°	



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